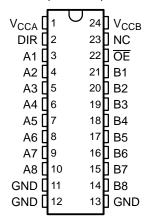
SCAS585O-NOVEMBER 1996-REVISED MARCH 2005

FEATURES

- Bidirectional Voltage Translator
- 2.3 V to 3.6 V on A Port and 3 V to 5.5 V on B Port
- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCA} Voltage
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DB, DBQ, DW, NS, OR PW PACKAGE (TOP VIEW)



NC - No internal connection

DESCRIPTION/ORDERING INFORMATION

This 8-bit (octal) noninverting bus transceiver contains two separate supply rails. The B port is designed to track V_{CCB} , which accepts voltages from 3 V to 5.5 V, and the A port is designed to track V_{CCA} , which operates at 2.3 V to 3.6 V. This allows for translation from a 3.3-V to a 5-V system environment and vice versa, from a 2.5-V to a 3.3-V system environment and vice versa.

The SN74LVCC3245A is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated. The control circuitry (DIR, \overline{OE}) is powered by V_{CCA} .

ORDERING INFORMATION

T _A	PACKA	3E ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube of 25	SN74LVCC3245ADW	LVCC3245A
	SOIC - DVV	Reel of 2000	SN74LVCC3245ADWR	LVCC3245A
	SOP - NS	Reel of 2000	SN74LVCC3245ANSR	LVCC3245A
400C to 050C	SSOP - DB	Reel of 2000	SN74LVCC3245ADBR	LH245A
–40°C to 85°C	SSOP (QSOP) – DBQ	Reel of 2500	SN74LVCC3245ADBQR	LVCC3245A
		Tube of 60	SN74LVCC3245APW	
	TSSOP - PW	Reel of 2000	SN74LVCC3245APWR	LH245A
		Reel of 250	SN74LVCC3245APWT	

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (EACH TRANSCEIVER)

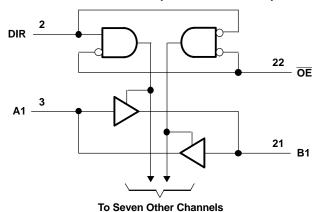
INP	UTS	OPERATION
ŌĒ	DIR	OPERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	X	Isolation



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V_{CCA}	Supply voltage range		-0.5	6	V	
		All A ports ⁽²⁾	-0.5	V _{CCA} + 0.5		
V_{I}	Input voltage range	All B ports ⁽³⁾	-0.5	V _{CCB} + 0.5	V	
		Except I/O ports ⁽²⁾	-0.5	V _{CCA} + 0.5		
V	Output values =(3)	All A ports	-0.5	V _{CCA} + 0.5	V	
V _O	Output voltage range ⁽³⁾	All B ports	-0.5	V _{CCB} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA	
I _{OK}	Output clamp current	V _O < 0		-50	mA	
Io	Continuous output current			±50	mA	
	Continuous current through V _{CCA} , V _{CCB} , or	GND		±100	mA	
		DB package		63		
		DBQ package		61		
θ_{JA}	Package thermal impedance (4)	DW package		46	°C/W	
		NS package		65		
		PW package		88		
T _{stg}	Storage temperature range		-65	150	°C	

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ This value is limited to 4.6 V maximum.

⁽³⁾ This value is limited to 6 V maximum.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



SCAS585O-NOVEMBER 1996-REVISED MARCH 2005

Recommended Operating Conditions⁽¹⁾

		V _{CCA}	V _{CCB}	MIN	NOM	MAX	UNIT	
V_{CCA}	Supply voltage			2.3	3.3	3.6	V	
V_{CCB}	Supply voltage			3	5	5.5	V	
		2.3 V	3 V	1.7				
.,	High-level input voltage	2.7 V	3 V	2			V	
V_{IHA}	nigh-level input voltage	3 V	3.6 V	2			V	
		3.6 V	5.5 V	2				
		2.3 V	3 V	2				
.,	High level input voltage	2.7 V	3 V	2			V	
√ _{IHB}	High-level input voltage	3 V	3.6 V	2			V	
		3.6 V	5.5 V	3.85				
		2.3 V	3 V			0.7		
. ,	Low lovel input voltage	2.7 V	3 V			8.0	V	
I_{ILA}	Low-level input voltage	3 V	3.6 V			0.8	V	
		3.6 V	5.5 V			0.8		
		2.3 V	3 V			0.8		
,	Law law Panatas Itana	2.7 V	3 V			0.8	.,	
I_{ILB}	Low-level input voltage	3 V	3.6 V			0.8	V	
		3.6 V	5.5 V			1.65		
		2.3 V	3 V	1.7				
√ _{IH}	High-level input voltage (control pins)	2.7 V	3 V	2			.,	
	(referenced to V _{CCA})	3 V	3.6 V	2			V	
		3.6 V	5.5 V	2				
		2.3 V	3 V			0.7		
	Low-level input voltage (control pins)	2.7 V	3 V			0.8		
√ _{IL}	(referenced to V _{CCA})	3 V	3.6 V			0.8	V	
		3.6 V	5.5 V			0.8		
V _{IA}	Input voltage			0		V_{CCA}	V	
V _{IB}	Input voltage			0		V _{CCB}	V	
V _{OA}	Output voltage			0		V _{CCA}	V	
V _{OB}	Output voltage			0		V _{CCB}	V	
0.0	·	2.3 V	3 V			-8		
		2.7 V	3 V			-12		
ОНА	High-level output current	3 V	3 V			-24	mA	
		2.7 V	4.5 V			-24		
		2.3 V	3 V			-12		
		2.7 V	3 V			-12		
ОНВ	High-level output current	3 V	3 V			-24	mA	
		2.7 V	4.5 V			-24	Ì	
		2.3 V	3 V			8		
		2.7 V	3 V			12		
OLA	Low-level output current	3 V	3 V			24	mA	
		2.7 V	4.5 V			24		

⁽¹⁾ All unused inputs of the device must be held at the associated V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



SCAS5850-NOVEMBER 1996-REVISED MARCH 2005

Recommended Operating Conditions (continued)

		V _{CCA}	V _{CCB}	MIN NOM	MAX	UNIT
I _{OLB} Low-level output current		2.3 V	3 V		12	
	2.7 V	3 V		12	mΛ	
OLB		3 V	3 V		24	mA
		2.7 V	4.5 V		24	
Δt/Δν	Input transition rise or fall rate				10	ns/V
T _A	Operating free-air temperature			-40	85	°C



SCAS585O-NOVEMBER 1996-REVISED MARCH 2005

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDITIONS	V _{CCA}	V _{CCB}	MIN	TYP	MAX	UNIT	
		$I_{OH} = -100 \mu\text{A}$	3 V	3 V	2.9	3			
		$I_{OH} = -8 \text{ mA}$	2.3 V	3 V	2				
V _{OHA}		12 mA	2.7 V	3 V	2.2	2.5		\/	
VOHA		$I_{OH} = -12 \text{ mA}$	3 V	3 V	2.4	2.8		V	
		1 24 mA	3 V	3 V	2.2	2.6			
		$I_{OH} = -24 \text{ mA}$	2.7 V	4.5 V	2	2.3			
		$I_{OH} = -100 \mu\text{A}$	3 V	3 V	2.9	3			
		12 mA	2.3 V	3 V	2.4				
V_{OHB}		$I_{OH} = -12 \text{ mA}$	2.7 V	3 V	2.4	2.8		V	
▼OHB		1 24 mA	3 V	3 V	2.2	2.6			
		$I_{OH} = -24 \text{ mA}$	2.7 V	4.5 V	3.2	4.2			
		I _{OL} = 100 μA	3 V	3 V			0.1		
		I _{OL} = 8 mA	2.3 V	3 V			0.6		
V_{OLA}		I _{OL} = 12 mA	2.7 V	3 V		0.1	0.5	V	
V _{OLA}		1 04 1	3 V	3 V		0.2	0.5		
		I _{OL} = 24 mA	2.7 V	4.5 V		0.2	0.5		
		I _{OL} = 100 μA	3 V	3 V			0.1		
V		I _{OL} = 12 mA	2.3 V	3 V			0.4	.,	
V _{OLB}	OLB	1 04 1	3 V	3 V		0.2	0.5	V	
		$I_{OL} = 24 \text{ mA}$	2.7 V	4.5 V		0.2	0.5		
		V V 0VD	0.01/	3.6 V		±0.1	±1		
I _I	Control inputs	$V_I = V_{CCA}$ or GND	3.6 V	5.5 V		±0.1	±1	μΑ	
I _{OZ} ⁽¹⁾	A or B ports	$V_O = V_{CCA/B}$ or GND, $V_I = V_{IL}$ or V_{IH}	3.6 V	3.6 V		±0.5	±5	μΑ	
		A port = V_{CCA} or GND, $I_O = 0$	3.6 V	Open		5	50		
I _{CCA}	B to A	D. J. V. OND. J. O	0.01/	3.6 V		5	50	μΑ	
		B port = V_{CCB} or GND, $I_O = 0$	3.6 V	5.5 V		5	50		
			2.21/	3.6 V		5	50		
ICCB	A to B	A port = V_{CCA} or GND, $I_O = 0$	3.6 V	5.5 V		8	80	μΑ	
	A port	$\frac{V_{I}}{OE}$ = V _{CCA} - 0.6 V, Other inputs at V _{CCA} or GND, $\frac{V_{CCA}}{OE}$ at GND and DIR at V _{CCA}	3.6 V	3.6 V		0.35	0.5		
ΔI _{CCA} ⁽²⁾		$V_{\rm I}$ = $V_{\rm CCA}$ – 0.6 V, Other inputs at $V_{\rm CCA}$ or GND, DIR at $V_{\rm CCA}$	3.6 V	3.6 V		0.35	0.5	mA	
	DIR	$\frac{V_{I}}{OE}$ = V_{CCA} – 0.6 V, Other inputs at V_{CCA} or GND, \overline{OE} at GND	3.6 V	3.6 V		0.35	0.5		
$\Delta I_{CCB}^{(2)}$	B port	$\frac{V_{I}}{OE}$ = V_{CCB} - 2.1 V, Other inputs at V_{CCB} or GND, \overline{OE} at GND and DIR at GND	3.6 V	5.5 V		1	1.5	mA	
C _i	Control inputs	V _I = V _{CCA} or GND	Open	Open		4		pF	
C _{io}	A or B ports	$V_O = V_{CCA/B}$ or GND	3.3 V	5 V		18.5		pF	

 ⁽¹⁾ For I/O ports, the parameter I_{OZ} includes the input leakage current.
(2) This is the increase in supply current for each input that is at one of the specified voltage levels, rather than 0 V or the associated V_{CC}.

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SCAS5850-NOVEMBER 1996-REVISED MARCH 2005

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 4)

PARAMETER	FROM (INPUT)			\pm 0.2 V,		$V_{CCA} = 2.7 \text{ V TO} \\ 3.6 \text{ V,} \\ V_{CCB} = 5 \text{ V} \\ \pm 0.5 \text{ V}$		3.6 V,		
			MIN	MAX	MIN	MAX	MIN	MAX		
t _{PHL}	А	В	1	9.4	1	6	1	7.1	20	
t _{PLH}	A	Ь	1	9.1	1	5.3	1	7.2	ns	
t _{PHL}	В	Α	1	11.2	1	5.8	1	6.4	20	
t _{PLH}	Ь	A	1	9.9	1	7	1	7.6	ns	
t _{PZL}	ŌĒ	۸	1	14.5	1	9.2	1	9.7	20	
t _{PZH}	OE	Α	1	12.9	1	9.5	1	9.5	ns	
t _{PZL}	ŌĒ	В	1	13	1	8.1	1	9.2	20	
t _{PZH}	OE	В	1	12.8	1	8.4	1	9.9	ns	
t _{PLZ}	ŌĒ	^	1	7.1	1	7	1	6.6		
t _{PHZ}	UE	Α	1	6.9	1	7.8	1	6.9	ns)	
t _{PLZ}	ŌĒ	D	1	8.8	1	7.3	1	7.5		
t _{PHZ}	OE .	В	1	8.9	1	7	1	7.9	ns	

Operating Characteristics

 $V_{CCA} = 3.3 \text{ V}, V_{CCB} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER		TEST C	ONDITIONS	TYP	UNIT
_	Dower dissination conscitance nor transceiver	Outputs enabled	C 50	f 10 MHz	38	. ۲
Cpd	Power dissipation capacitance per transceiver	Outputs disabled	$C_L = 50,$	f = 10 MHz	4.5	pF

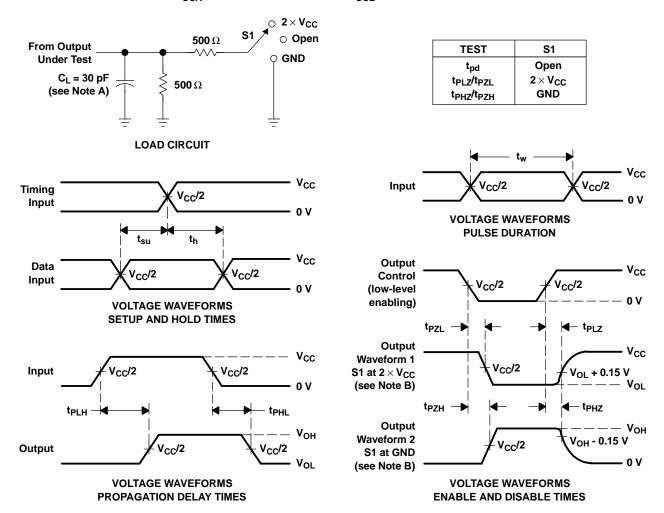
Power-Up Considerations(1)

TI level-translation devices offer an opportunity for successful mixed-voltage signal design. A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies caused by improperly biased device pins. To guard against such power-up problems, take these precautions:

- 1. Connect ground before any supply voltage is applied.
- 2. Power up the control side of the device (V_{CCA} for all four of these devices).
- 3. Tie \overline{OE} to V_{CCA} with a pullup resistor so that it ramps with V_{CCA} .
- 4. Depending on the direction of the data path, DIR can be high or low. If DIR high is needed (A data to B bus), ramp it with V_{CCA} . Otherwise, keep DIR low.
- (1) Refer to the TI application report, Texas Instruments Voltage-Level-Translation Devices, literature number SCEA021.

SCAS585O-NOVEMBER 1996-REVISED MARCH 2005

PARAMETER MEASUREMENT INFORMATION FOR A PORT V_{CCA} = 2.5 V \pm 0.2 V AND V_{CCB} = 3.3 V \pm 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

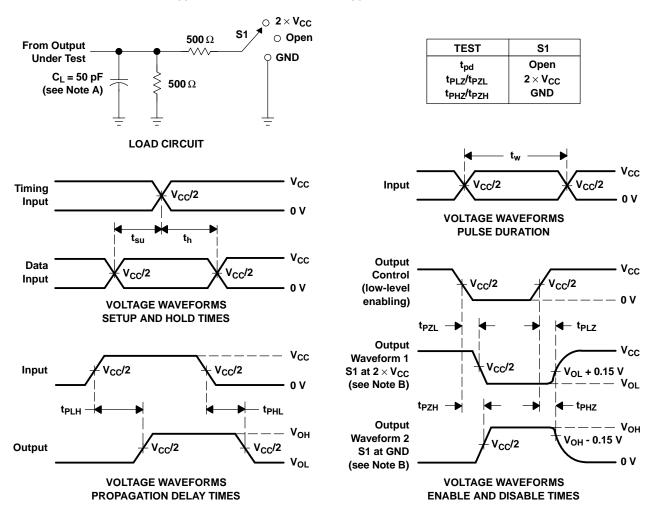
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

SCAS5850-NOVEMBER 1996-REVISED MARCH 2005



PARAMETER MEASUREMENT INFORMATION FOR B PORT V_{CCA} = 2.5 V \pm 0.2 V AND V_{CCB} = 3.3 V \pm 0.3 V

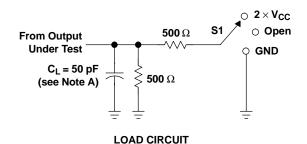


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd}.
 - H. All parameters and waveforms are not applicable to all devices.

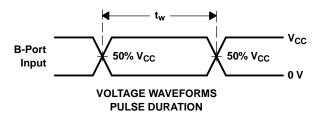
Figure 2. Load Circuit and Voltage Waveforms

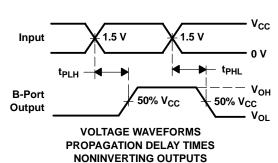
SCAS585O-NOVEMBER 1996-REVISED MARCH 2005

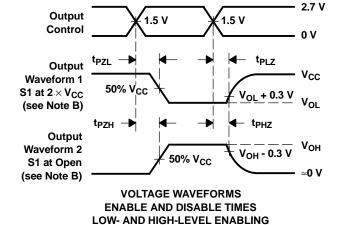
PARAMETER MEASUREMENT INFORMATION FOR B PORT $V_{\text{CCA}} = 3.6 \text{ V}$ and $v_{\text{CCB}} = 5.5 \text{ V}$



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	2×V _{CC}
t _{PHZ} /t _{PZH}	Open







NOTES: A. C_L includes probe and jig capacitance.

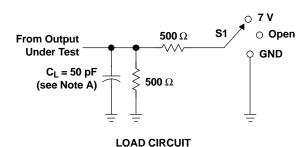
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_{\Omega} = 50~\Omega$, $t_r \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

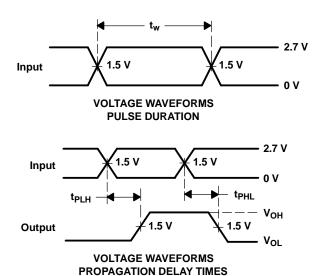
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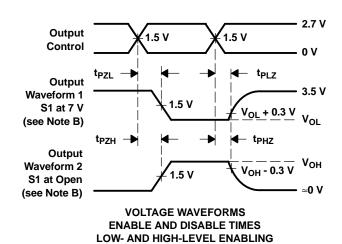


PARAMETER MEASUREMENT INFORMATION FOR A AND B PORT V_{CCA} AND V_{CCB} = 3.6 V



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	7 V
t _{PHZ} /t _{PZH}	Open





NOTES: A. C_L includes probe and jig capacitance.

NONINVERTING OUTPUTS

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

13-Oct-2012

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
74LVCC3245ADBQRE4	ACTIVE	SSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
74LVCC3245ADBQRG4	ACTIVE	SSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SN74LVCC3245ADBLE	OBSOLETE	SSOP	DB	24		TBD	Call TI	Call TI	
SN74LVCC3245ADBQR	ACTIVE	SSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SN74LVCC3245ADBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADBRE4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADBRG4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ADWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ANSR	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ANSRE4	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245ANSRG4	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	





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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74LVCC3245APWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APWLE	OBSOLETE	TSSOP	PW	24		TBD	Call TI	Call TI	
SN74LVCC3245APWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APWT	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APWTE4	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCC3245APWTG4	ACTIVE	TSSOP	PW	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

13-Oct-2012

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OTHER QUALIFIED VERSIONS OF SN74LVCC3245A:

■ Enhanced Product: SN74LVCC3245A-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCC3245ADBQR	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVCC3245ADBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74LVCC3245ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVCC3245ADWRG4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVCC3245ANSR	SO	NS	24	2000	330.0	24.4	8.2	15.4	2.5	12.0	24.0	Q1
SN74LVCC3245APWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVCC3245APWT	TSSOP	PW	24	250	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

www.ti.com 13-Oct-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74LVCC3245ADBQR	SSOP	DBQ	24	2500	367.0	367.0	38.0	
SN74LVCC3245ADBR	SSOP	DB	24	2000	367.0	367.0	38.0	
SN74LVCC3245ADWR	SOIC	DW	24	2000	367.0	367.0	45.0	
SN74LVCC3245ADWRG4	SOIC	DW	24	2000	367.0	367.0	45.0	
SN74LVCC3245ANSR	SO	NS	24	2000	367.0	367.0	45.0	
SN74LVCC3245APWR	TSSOP	PW	24	2000	367.0	367.0	38.0	
SN74LVCC3245APWT	TSSOP	PW	24	250	367.0	367.0	38.0	

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE

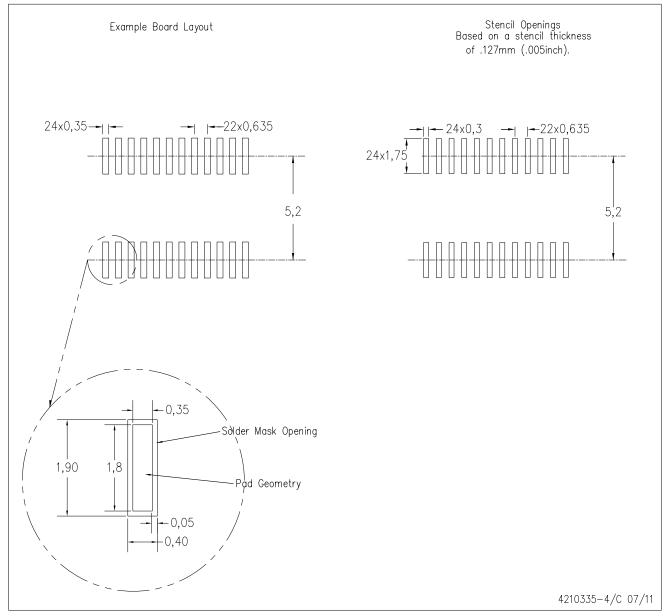


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AE.



DBQ (R-PDSO-G24)

PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE

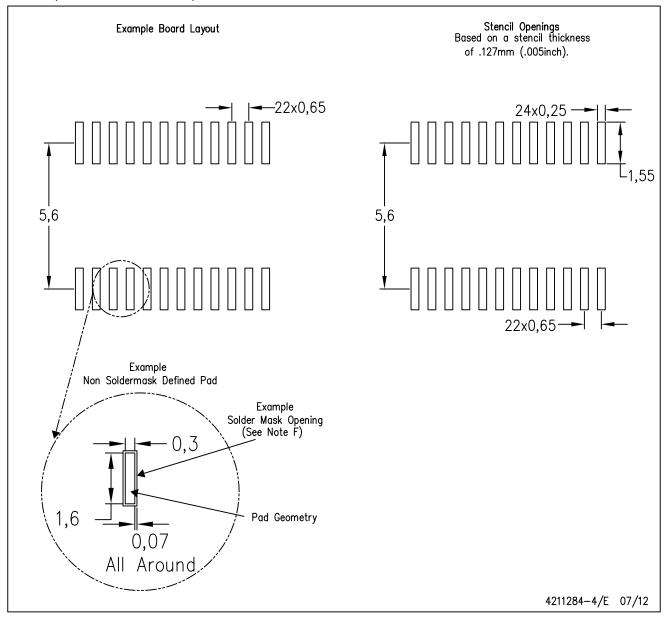


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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